





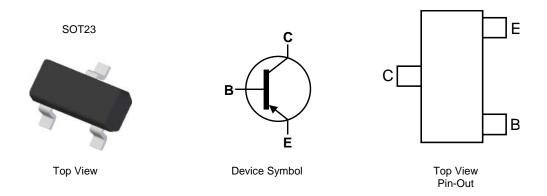
12V PNP HIGH GAIN MEDIUM POWER TRANSISTOR IN SOT23

Features

- BV_{CEO} > -12V
- I_C = -1.25A Continuous Collector Current
- I_{CM} = -4A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -240mV @ -1A
- $R_{CE(SAT)} = 160 \text{m}\Omega$ for a low equivalent on-resistance
- 500mW power dissipation
- hFE characterised up to -3A for high current gain hold-up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (approximate)



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMTL717TA	AEC-Q101	L77	7	8	3,000
FMMTL717QTA	Automotive	L77	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-12	V
Collector-Emitter Voltage	V_{CEO}	-12	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-1.25	Α
Peak Pulse Current	I _{CM}	-4	Α
Base Current	Ι _Β	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P _D	500	mW
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead	(Note 7)	R _{0JL}	197	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

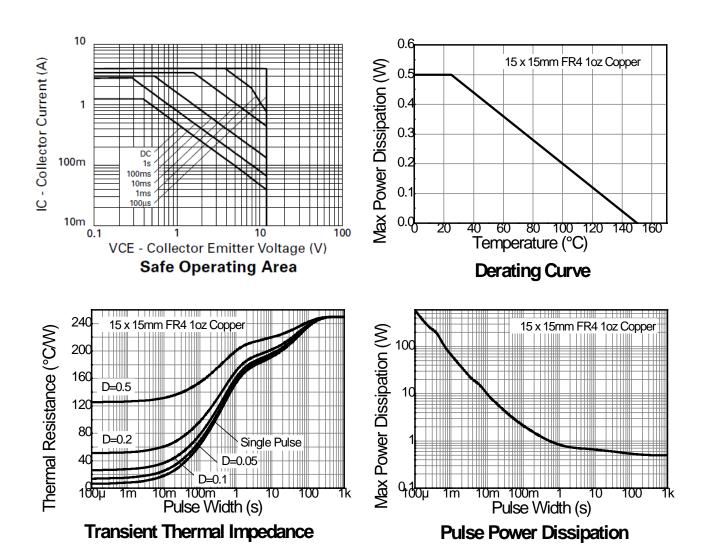
- 6. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating information





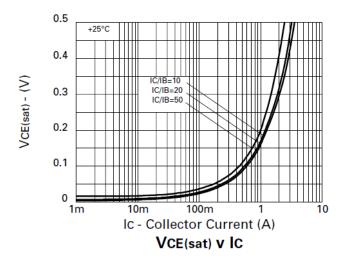
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

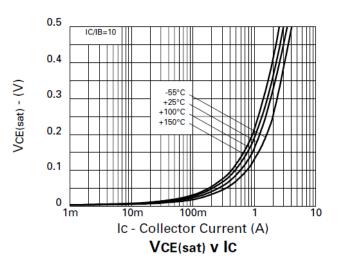
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	-12	-35	-	٧	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-12	-25	-	V	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.5	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I _{CBO}	-	<-1	-10	nA	V _{CB} = -10V
Emitter Cutoff Current	I _{EBO}	-	<-1	-10	nA	$V_{EB} = -5.6V$
Collector Emitter Cutoff Current	I _{CES}	-	<-1	-10	nA	V _{CE} = -10V
		300	490	-		$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
		300	450	-	-	I _C = -0.1A, V _{CE} = -2V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	180	275	-		I _C = -1A, V _{CE} = -2V
		100	180	-		I _C = -2A, V _{CE} = -2V
		50	110	-		I _C = -3A, V _{CE} = -2V
		-	-24	-40	mV	I _C =- 0.1A, I _B = -10mA
Callactor Emitter Seturation Voltage (Note O)	V _{CE(sat)}	-	-94	-140	mV	$I_C = -0.5A$, $I_B = -20mA$
Collector-Emitter Saturation Voltage (Note 9)		-	-160	-240	mV	$I_C = -1A$, $I_B = -50mA$
		-	-200	-290	mV	$I_C = -1.25A$, $I_B = -50mA$
Base-Emitter Turn-On Voltage(Note 9)	V _{BE(on)}	-	-875	-1000	mV	I _C = -1.25A, V _{CE} = -2V
Base-Emitter Saturation Voltage(Note 9)	V _{BE(sat)}	-	-970	-1100	mV	$I_C = -1.25A$, $I_B = -50mA$
Output Capacitance	C _{obo}	-	15	20	pF	V _{CB} = -10V, f = 1MHz
Transition Frequency	f⊤	-	205	-	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Turn-On Time	t _{on}	-	76	-	ns	$V_{CC} = -10V, I_{C} = -1A$
Turn-Off Time	t _{off}	-	149	-	ns	$I_{B1} = -I_{B2} = -10mA$

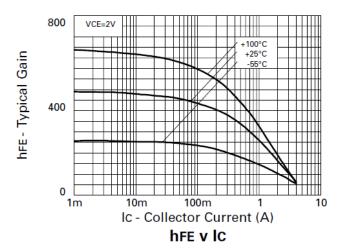
Notes: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

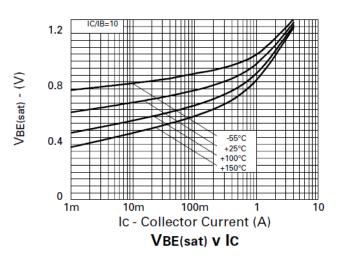


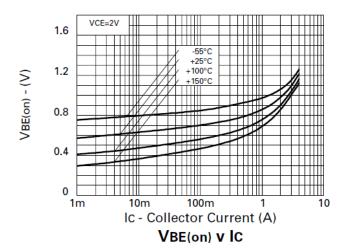
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







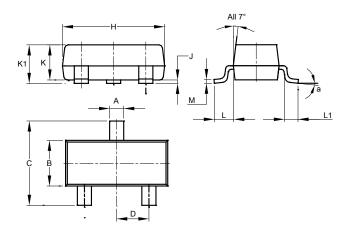






Package Outline Dimensions

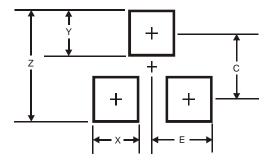
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	8°				
All	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
X	0.8		
Y	0.9		
С	2.0		
E	1.35		





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